ISO5500 SLLSE64D – SEPTEMBER 2011 – REVISED JANUARY 2015



**FEXAS** 

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## 9.2.2.13.1 Example

Reducing the peak charge current from the previous example to  $I_{ON-PK}$  = 1.5 A, requires a R<sub>C</sub> value of:

$$R_{\rm C} = 10 \ \Omega \times \left(\frac{2 \ {\rm A}}{1.5 \ {\rm A}} - 1\right) = 3.33 \ \Omega$$
 (13)

## 9.2.2.14 Higher Output Current Using an External Current Buffer

To increase the IGBT gate drive current, a non-inverting current buffer (such as the npn/pnp buffer shown in Figure 72) may be used. Inverting types are not compatible with the desaturation fault protection circuitry and must be avoided. The MJD44H11/MJD45H11 pair is appropriate for currents up to 8 A, the D44VH10/ D45VH10 pair for up to 15 A maximum.

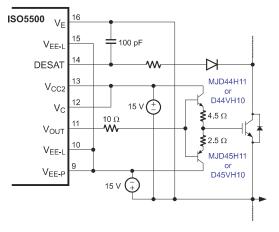


Figure 72. Current Buffer for Increased Drive Current

## 9.2.3 Application Curve

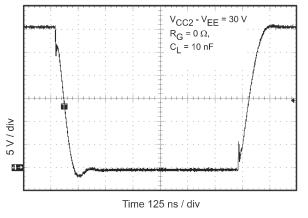


Figure 73. Output Waveform